



Chipsmall Limited consists of a professional team with an average of over 10 year of expertise in the distribution of electronic components. Based in Hongkong, we have already established firm and mutual-benefit business relationships with customers from,Europe,America and south Asia,supplying obsolete and hard-to-find components to meet their specific needs.

With the principle of “Quality Parts,Customers Priority,Honest Operation,and Considerate Service”,our business mainly focus on the distribution of electronic components. Line cards we deal with include Microchip,ALPS,ROHM,Xilinx,Pulse,ON,Everlight and Freescale. Main products comprise IC,Modules,Potentiometer,IC Socket,Relay,Connector.Our parts cover such applications as commercial,industrial, and automotives areas.

We are looking forward to setting up business relationship with you and hope to provide you with the best service and solution. Let us make a better world for our industry!



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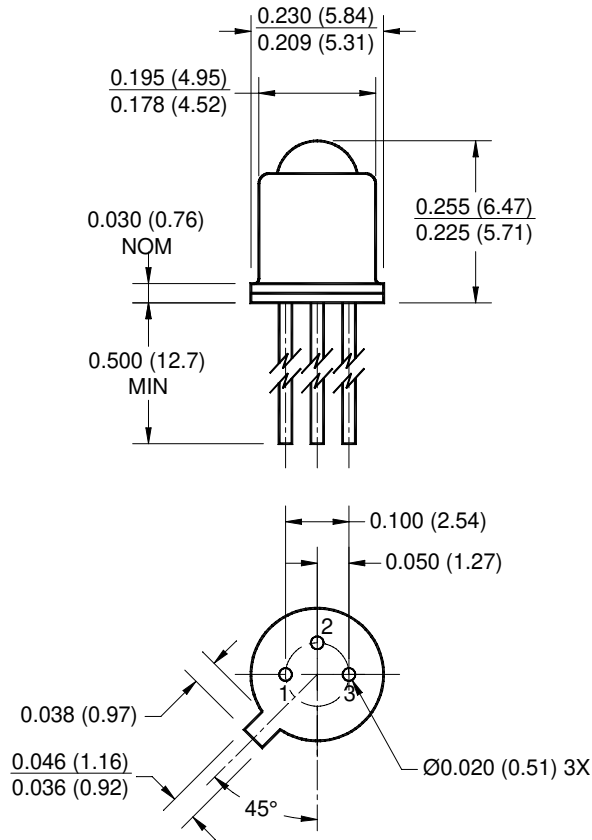
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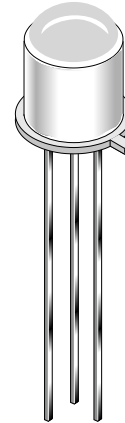


**PACKAGE DIMENSIONS**

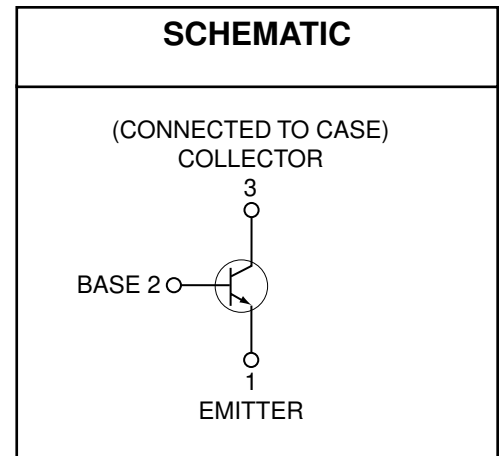


**NOTES:**

1. Dimensions for all drawings are in inches (mm).
2. Tolerance of  $\pm .010$  (.25) on all non-nominal dimensions unless otherwise specified.



**SCHEMATIC**



**DESCRIPTION**

The L14G1/L14G2/L14G3 are silicon phototransistors mounted in a narrow angle, TO-18 package.

**FEATURES**

- Hermetically sealed package
- Narrow reception angle

**L14G1 L14G2 L14G3**

<b>ABSOLUTE MAXIMUM RATINGS</b> ( $T_A = 25^\circ\text{C}$ unless otherwise specified)			
Parameter	Symbol	Rating	Unit
Operating Temperature	$T_{\text{OPR}}$	-65 to +125	$^\circ\text{C}$
Storage Temperature	$T_{\text{STG}}$	-65 to +150	$^\circ\text{C}$
Soldering Temperature (Iron) <sup>(3,4,5 and 6)</sup>	$T_{\text{SOL-I}}$	240 for 5 sec	$^\circ\text{C}$
Soldering Temperature (Flow) <sup>(3,4 and 6)</sup>	$T_{\text{SOL-F}}$	260 for 10 sec	$^\circ\text{C}$
Collector to Emitter Breakdown Voltage	$V_{\text{CEO}}$	45	V
Collector to Base Breakdown Voltage	$V_{\text{CBO}}$	45	V
Emitter to Base Breakdown Voltage	$V_{\text{EBO}}$	5	V
Power Dissipation ( $T_A = 25^\circ\text{C}$ ) <sup>(1)</sup>	$P_D$	300	mW
Power Dissipation ( $T_C = 25^\circ\text{C}$ ) <sup>(2)</sup>	$P_D$	600	mW

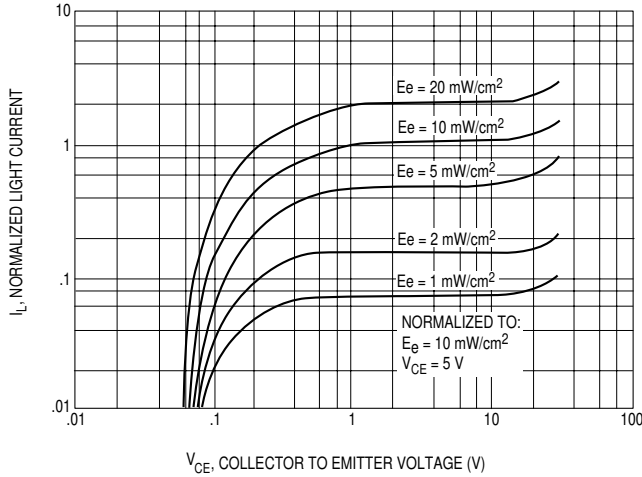
**NOTE:**

- Derate power dissipation linearly 3.00 mW/ $^\circ\text{C}$  above 25 $^\circ\text{C}$  ambient.
- Derate power dissipation linearly 6.00 mW/ $^\circ\text{C}$  above 25 $^\circ\text{C}$  case.
- RMA flux is recommended.
- Methanol or isopropyl alcohols are recommended as cleaning agents.
- Soldering iron tip 1/16" (1.6mm) minimum from housing.
- As long as leads are not under any stress or spring tension.
- Light source is a GaAs LED emitting light at a peak wavelength of 940 nm.
- Figure 1 and figure 2 use light source of tungsten lamp at 2870 $^\circ\text{K}$  color temperature. A GaAs source of 3.0 mW/cm<sup>2</sup> is approximately equivalent to a tungsten source, at 2870 $^\circ\text{K}$ , of 10 mW/cm<sup>2</sup>.

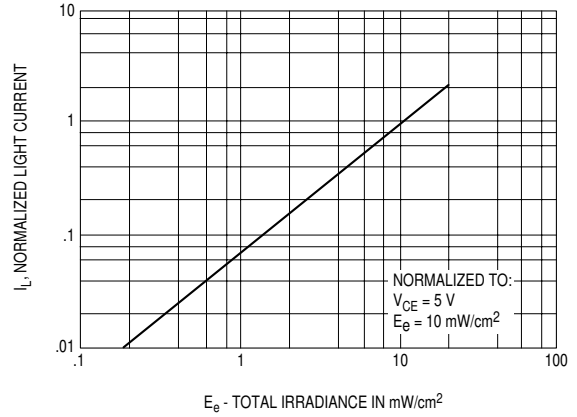
<b>ELECTRICAL / OPTICAL CHARACTERISTICS</b> ( $T_A = 25^\circ\text{C}$ ) (All measurements made under pulse conditions)						
PARAMETER	TEST CONDITIONS	SYMBOL	MIN	TYP	MAX	UNITS
Collector-Emitter Breakdown	$I_C = 10 \text{ mA}, E_e = 0$	$BV_{\text{CEO}}$	45		—	V
Emitter-Base Breakdown	$I_E = 100 \mu\text{A}, E_e = 0$	$BV_{\text{EBO}}$	5.0		—	V
Collector-Base Breakdown	$I_C = 100 \mu\text{A}, E_e = 0$	$BV_{\text{CBO}}$	45		—	V
Collector-Emitter Leakage	$V_{\text{CE}} = 10 \text{ V}, E_e = 0$	$I_{\text{CEO}}$	—		100	nA
Reception Angle at 1/2 Sensitivity		$\theta$		$\pm 10$		Degrees
On-State Collector Current L14G1	$E_e = 0.5 \text{ mW/cm}^2, V_{\text{CE}} = 5 \text{ V}^{(7,8)}$	$I_{\text{C(ON)}}$	1.0		—	mA
On-State Collector Current L14G2	$E_e = 0.5 \text{ mW/cm}^2, V_{\text{CE}} = 5 \text{ V}^{(7,8)}$	$I_{\text{C(ON)}}$	0.5			mA
On-State Collector Current L14G3	$E_e = 0.5 \text{ mW/cm}^2, V_{\text{CE}} = 5 \text{ V}^{(7,8)}$	$I_{\text{C(ON)}}$	2.0			mA
Turn-On Time	$I_C = 2 \text{ mA}, V_{\text{CC}} = 10 \text{ V}, R_L = 100 \Omega$	$t_{\text{on}}$		8		$\mu\text{s}$
Turn-Off Time	$I_C = 2 \text{ mA}, V_{\text{CC}} = 10 \text{ V}, R_L = 100 \Omega$	$t_{\text{off}}$		7		$\mu\text{s}$
Saturation Voltage	$I_C = 1.0 \text{ mA}, E_e = 3.0 \text{ mW/cm}^2^{(7,8)}$	$V_{\text{CE(SAT)}}$	—		0.40	V

**L14G1 L14G2 L14G3**

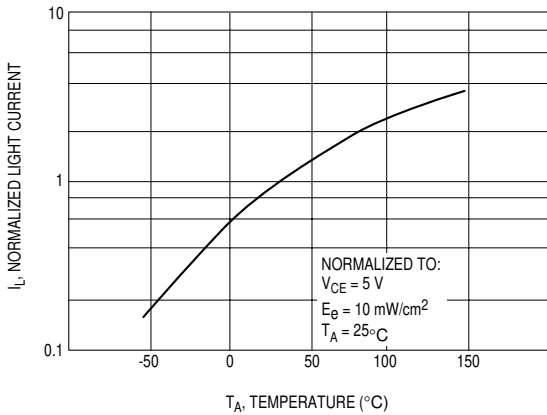
**Figure 1. Light Current vs. Collector to Emitter Voltage**



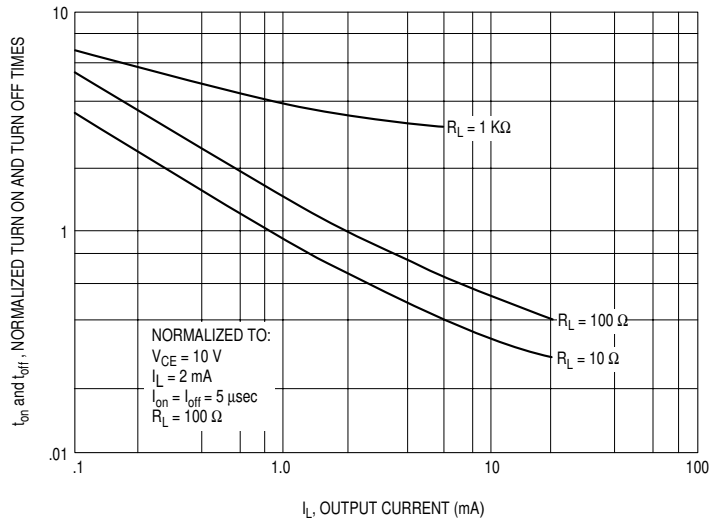
**Figure 2. Light Current vs. Temperature**



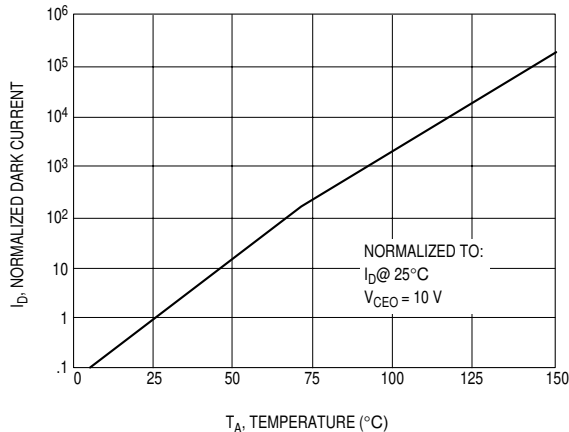
**Figure 3. Normalized Light Current vs. Temperature**



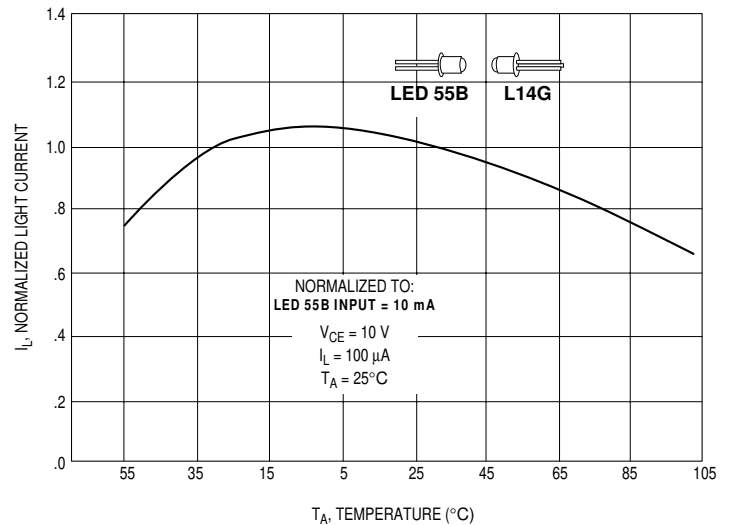
**Figure 4. Switching Times vs. Output Current**



**Figure 5. Dark Current and Temperature**



**Figure 6. Normalized Light Current vs. Temperature Both Emitter (LED 55B) and Detector (L14G) at Same Temperature**



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